

Substitute Form PTO-1449  
(Modified)U.S. Department of Commerce  
Patent and Trademark OfficeAttorney's Docket No.  
07977-226002Application No.  
09 596,755**Information Disclosure Statement  
by Applicant**

(Use several sheets if necessary)

(37 CFR § 1.98(b))

Applicant  
Hisashi OhtaniFiling Date  
June 15, 2000Group Art Unit  
1765**U.S. Patent Documents**

Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
/	AA	5 771 110	Jun 23, 1998	Hirano et al.			
/	AB	5 837 568	Nov 17, 1998	Yoneda et al.			
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						

**Foreign Patent Documents or Published Foreign Patent Applications**

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
/	AI	9-51099	2/18/97	Japan			ABS	
/	AJ	9-51100	2/18/97	Japan			ABS	
/	AK	9-74201 ✓	3/18/97	Japan			ABS	
/	AL	9-107108 ✓	4/22/97	Japan			ABS	
/	AM	9-237900 ✓	9/9/97	Japan			ABS	
/	AN	10-294469 ✓	11/4/98	Japan			ABS	
/	AO	2000-82822 ✓	3/21/00	Japan			ABS	
/	AP	2000-82821 ✓	3/21/00	Japan			ABS	

**Other Documents (include Author, Title, Date, and Place of Publication)**

Examiner Initial	Desig. ID	Document
/	AQ	Hatalis et al., "Solid phase crystallization of amorphous silicon by rapid thermal processing for flat panel display applications." Electrochemical Society Proceedings Volume 98-22, pp 92-99.
	AR	
	AS	

Examiner Signature

Date of Submission

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with examination report.